

BLF6G15L-500H; BLF6G15LS-500H

Power LDMOS transistor

Rev. 2 — 16 September 2011

Product data sheet

1. Product profile

1.1 General description

A 500 W LDMOS RF power transistor for transmitter applications and industrial applications. The transistor is optimized for digital applications and can deliver 65 W average DVB-T at 1.5 GHz. The excellent ruggedness of this device makes it ideal for digital transmitter applications.

Table 1. Test information

RF performance at $V_{DS} = 50\text{ V}$; $I_{DQ} = 1.3\text{ A}$.

Mode of operation	f (MHz)	$P_{L(AV)}$ (W)	G_p (dB)	η_D (%)	IMD3 (dBc)	IMD _{shldr} (dBc)	PAR (dB)
2-tone, class-AB	1452 to 1492	250	15	34	-24	-	-
DVB-T (8k OFDM)	1452 to 1492	65	16	19	-	-32 [1]	9 [2]

[1] Measured [dBc] with delta marker at 4.3 MHz from center frequency.

[2] PAR (of output signal) at 0.01 % probability on CCDF; PAR of input signal = 9.5 dB at 0.01 % probability on CCDF.

1.2 Features and benefits

- Easy power control
- Integrated ESD protection
- Excellent ruggedness
- High efficiency
- Excellent thermal stability
- Internally matched for ease of use
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

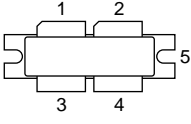
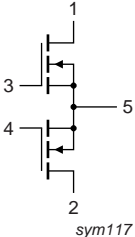
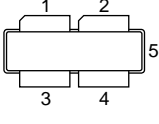
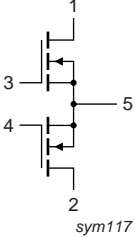
1.3 Applications

- Digital transmitter applications DVB at 1.5 GHz
- Industrial applications at 1.5 GHz



2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
BLF6G15L-500H (SOT539A)			
1	drain1		
2	drain2		
3	gate1		
4	gate2		
5	source		
BLF6G15LS-500H (SOT539B)			
1	drain1		
2	drain2		
3	gate1		
4	gate2		
5	source		

[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BLF6G15L-500H	-	flanged balanced LDMOST ceramic package; 2 mounting holes; 4 leads	SOT539A
BLF6G15LS-500H	-	earless flanged balanced LDMOST ceramic package; 4 leads	SOT539B

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage		-	100	V
V_{GS}	gate-source voltage		-0.5	+13	V
I_D	drain current		-	45	A
T_{stg}	storage temperature		-65	+150	°C
T_j	junction temperature		-	200	°C

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Typ	Unit
$R_{th(j-case)}$	thermal resistance from junction to case	$T_{case} = 85\text{ °C}; P_L = 65\text{ W}$	0.18	K/W

6. Characteristics

Table 6. DC characteristics

$T_j = 25\text{ °C}$; per section unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0\text{ V}; I_D = 2.7\text{ mA}$	100	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$V_{DS} = 10\text{ V}; I_D = 270\text{ mA}$	1.4	1.8	2.4	V
I_{DSS}	drain leakage current	$V_{GS} = 0\text{ V}; V_{DS} = 50\text{ V}$	-	-	2.8	μA
I_{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75\text{ V}; V_{DS} = 10\text{ V}$	38	42	-	A
I_{GSS}	gate leakage current	$V_{GS} = 11\text{ V}; V_{DS} = 0\text{ V}$	-	-	280	nA
g_{fs}	forward transconductance	$V_{DS} = 10\text{ V}; I_D = 270\text{ mA}$	1.33	2.3	-	S
$R_{DS(on)}$	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75\text{ V}; I_D = 9.5\text{ A}$	-	100	193	$\text{m}\Omega$

Table 7. RF characteristics

RF characteristics in NXP class-AB production circuit, in frequency range 1452 MHz to 1492 MHz; $T_{case} = 25\text{ °C}$.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
DVB-T (8k OFDM), class-AB						
V_{DS}	drain-source voltage		-	50	-	V
I_{Dq}	quiescent drain current		-	1.3	-	A
$P_{L(AV)}$	average output power		-	65	-	W
G_p	power gain		14.5	16	-	dB
η_D	drain efficiency		16	19	-	%
IMD_{shldr}	intermodulation distortion shoulder		[1]	-32	-30	dBc
PAR	peak-to-average ratio		[2]	8.5	9	dB

[1] Measured [dBc] with delta marker at 4.3 MHz from center frequency.

[2] PAR (of output signal) at 0.01 % probability on CCDF; PAR of input signal = 9.5 dB at 0.01 % probability on CCDF.

6.1 Ruggedness in class-AB operation

The BLF6G15L-500H and BLF6G15LS-500H are capable of withstanding a load mismatch corresponding to $V_{SWR} = 10 : 1$ through all phases under the following conditions: $V_{DS} = 50\text{ V}$; $I_{Dq} = 1.3\text{ A}$ at rated power.

7. Application information

7.1 Impedance information

Table 8. Typical impedance
Typical values per section unless otherwise specified.

f MHz	Z _S Ω	Z _L Ω
1452	1.226 - j2.663	2.137 - j2.750
1472	1.375 - j2.757	1.869 - j2.378
1492	1.15 - j2.735	1.817 - j2.684

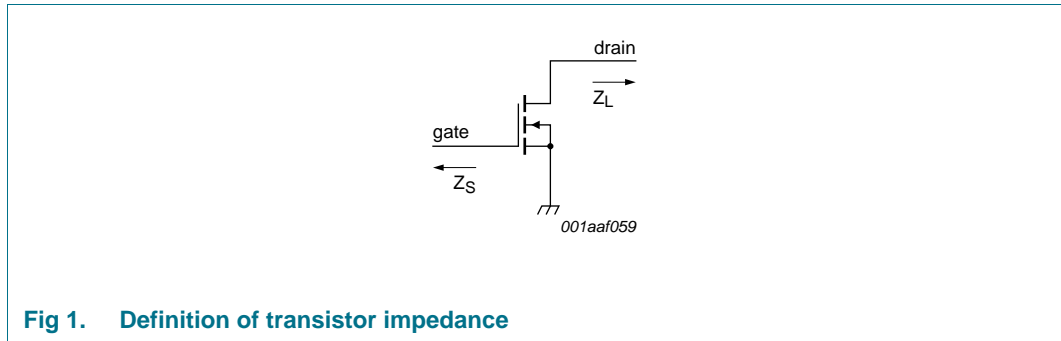
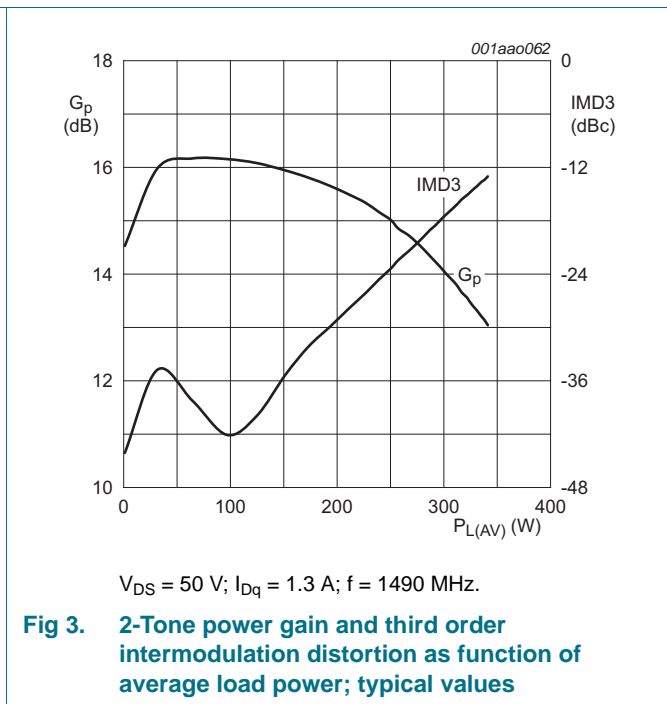
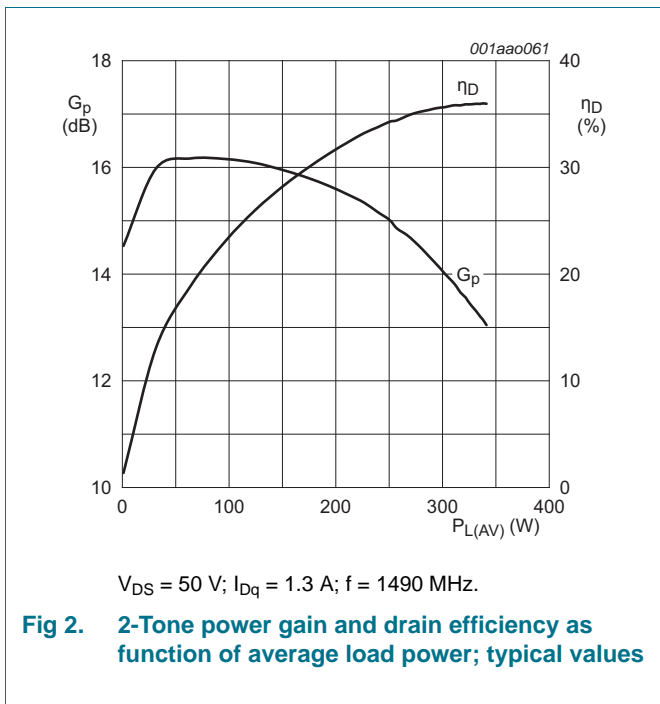


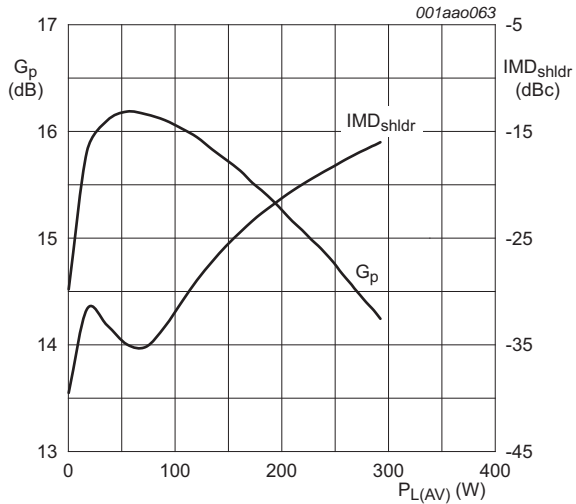
Fig 1. Definition of transistor impedance

7.2 Graphs

7.2.1 2-Tone

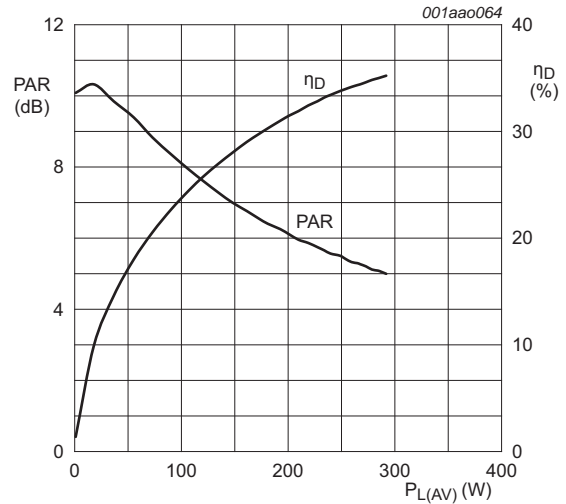


7.2.2 DVB-T



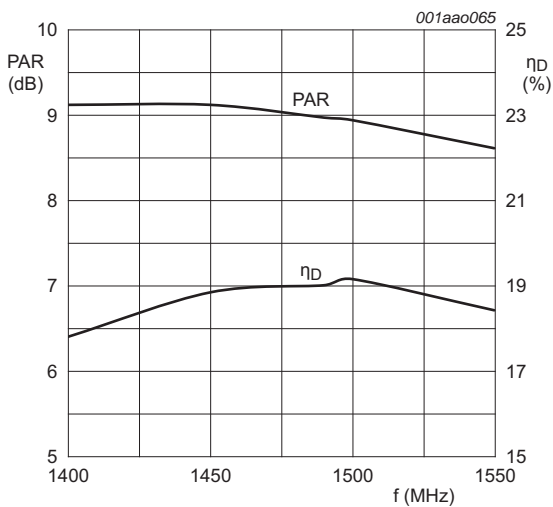
$V_{DS} = 50\text{ V}$; $I_{Dq} = 1.3\text{ A}$; $f = 1490\text{ MHz}$.

Fig 4. DVB-T power gain and intermodulation distortion shoulder as function of average load power; typical values



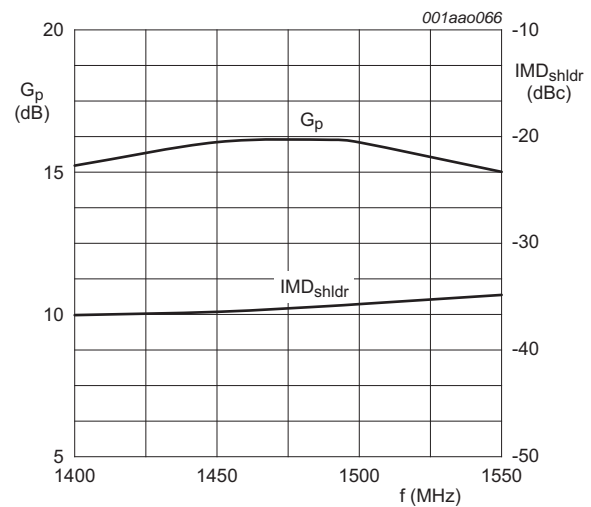
$V_{DS} = 50\text{ V}$; $I_{Dq} = 1.3\text{ A}$; $f = 1490\text{ MHz}$.

Fig 5. DVB-T peak-to-average ratio and drain efficiency as function of average load power; typical values



$V_{DS} = 50\text{ V}$; $I_{Dq} = 1.3\text{ A}$; $P_{L(AV)} = 65\text{ W}$.

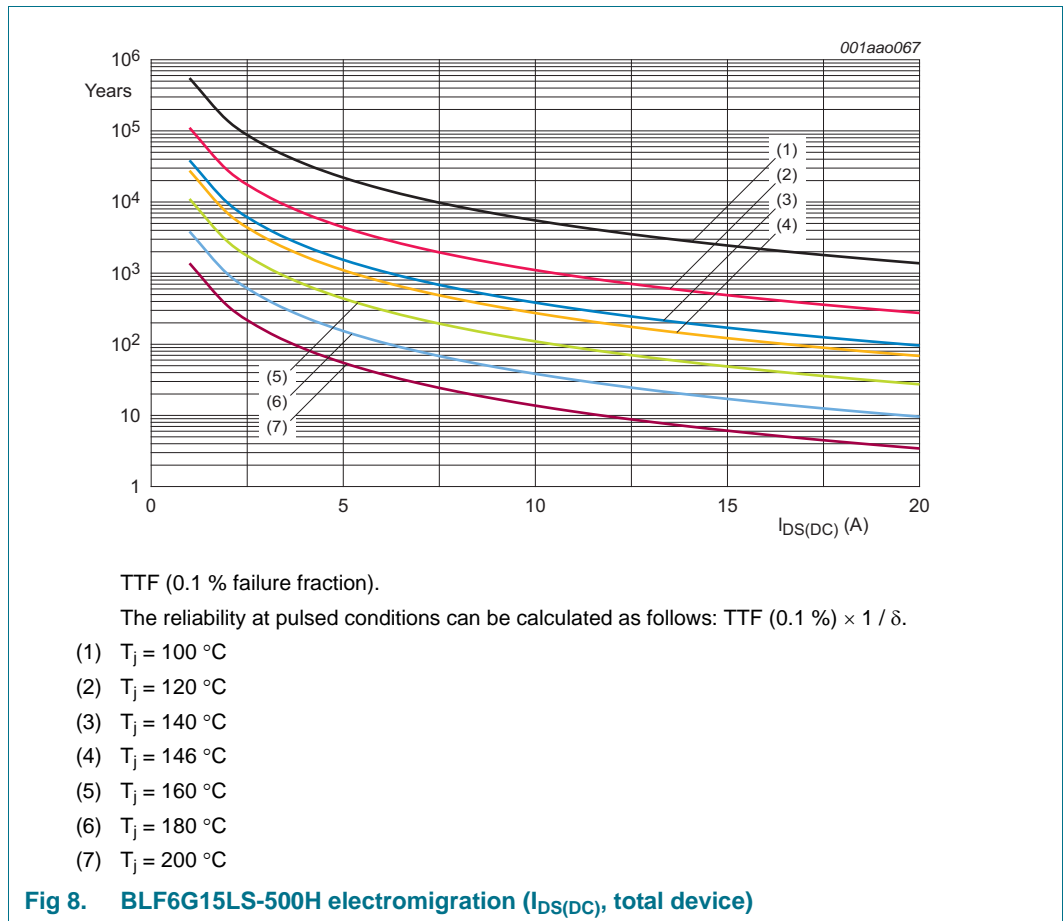
Fig 6. DVB-T peak-to-average ratio and drain efficiency as function of frequency; typical values



$V_{DS} = 50\text{ V}$; $I_{Dq} = 1.3\text{ A}$; $P_{L(AV)} = 65\text{ W}$.

Fig 7. DVB-T power gain and intermodulation distortion shoulder as function of frequency; typical values

7.2.3 Reliability



7.3 Test circuit

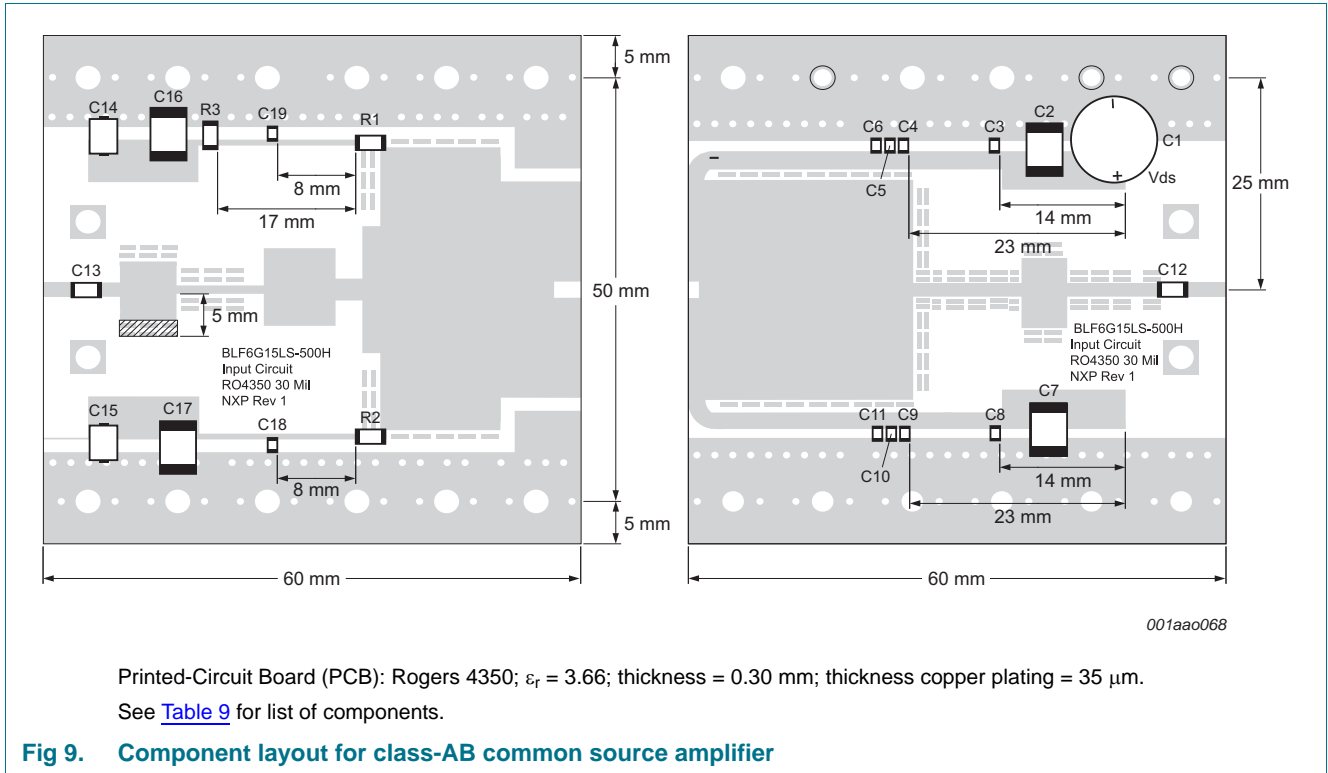


Table 9. List of components
 See [Figure 9](#) for component layout.

Component	Description	Value	Remarks
C1	electrolytic capacitor	470 μF , 63 V	Elco
C2, C7, C16, C17	multilayer ceramic chip capacitor	10 μF	TDK
C3, C8	multilayer ceramic chip capacitor	6.2 pF	ATC800B
C4, C5, C9, C10	multilayer ceramic chip capacitor	1.0 μF	1206 10 %
C6, C11	multilayer ceramic chip capacitor	10 nF	1205 10 %
C12, C13	multilayer ceramic chip capacitor	22 pF	ATC800B
C18, C19	multilayer ceramic chip capacitor	22 pF	ATC800B
C15	electrolytic capacitor	470 μF ; 63 V	
R1, R2	SMD resistor	5R1 Ω	0805
R3	SMD resistor	470 Ω (not fitted)	1206

8. Package outline

Flanged balanced LDMOST ceramic package; 2 mounting holes; 4 leads

SOT539A

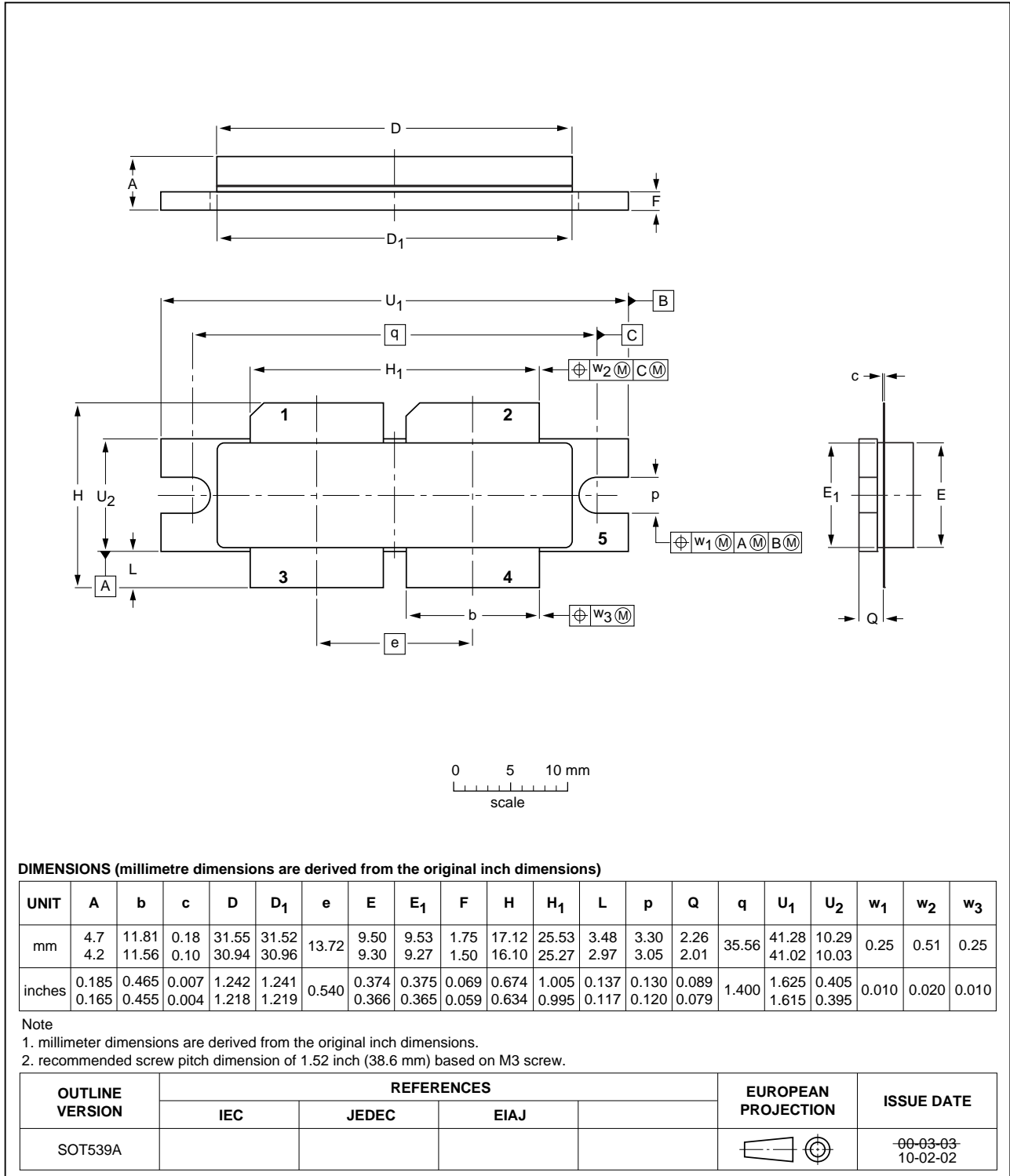


Fig 10. Package outline SOT539A

Earless flanged balanced LDMOST ceramic package; 4 leads

SOT539B

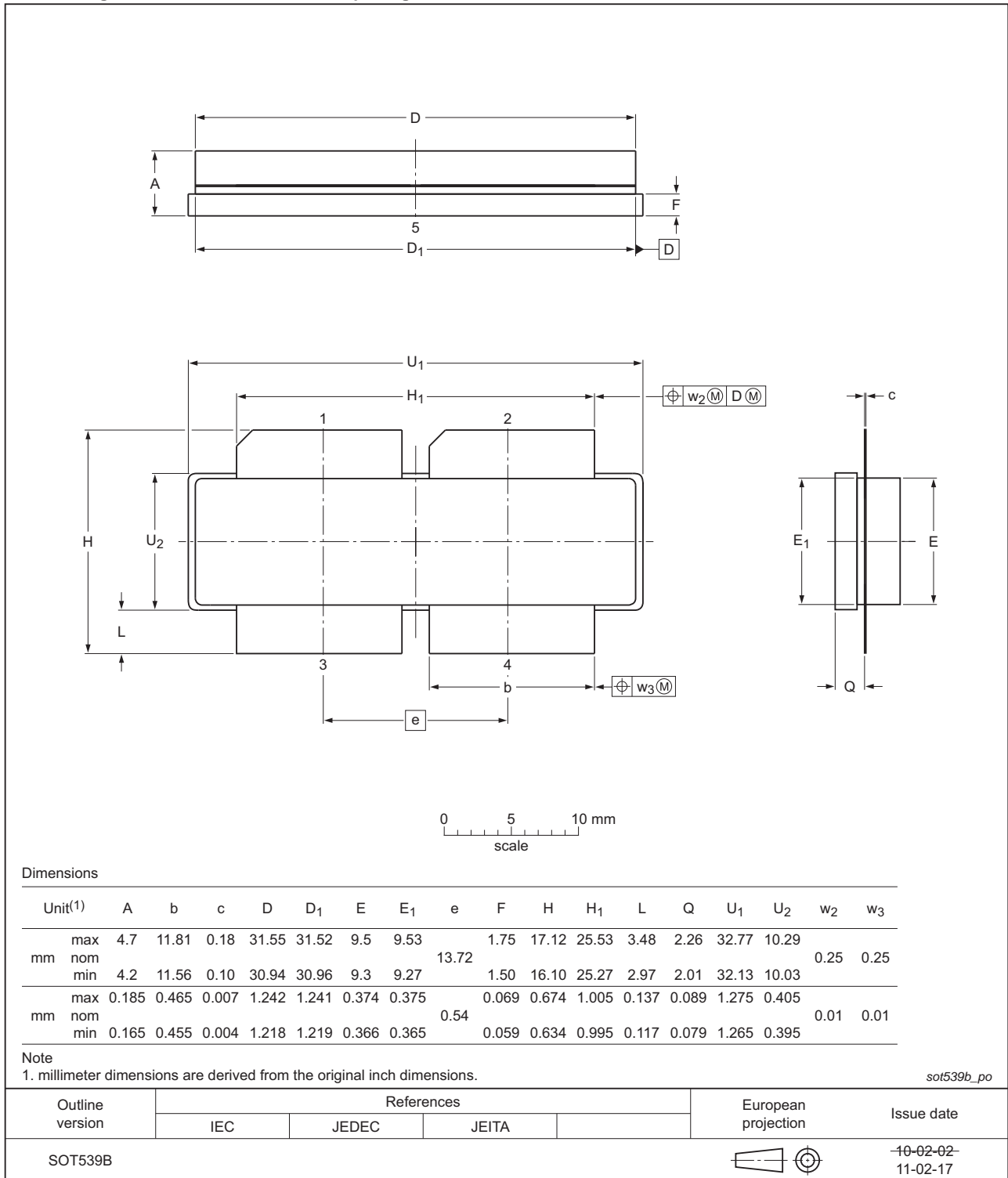


Fig 11. Package outline SOT539B

9. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the *ANSI/ESD S20.20*, *IEC/ST 61340-5*, *JESD625-A* or equivalent standards.

10. Abbreviations

Table 10. Abbreviations

Acronym	Description
CCDF	Complementary Cumulative Distribution Function
DVB-T	Digital Video Broadcast - Terrestrial
DVB	Digital Video Broadcast
ESD	ElectroStatic Discharge
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
LDMOST	Laterally Diffused Metal-Oxide Semiconductor Transistor
OFDM	Orthogonal Frequency Division Multiplexing
PAR	Peak-to-Average power Ratio
RF	Radio Frequency
SMD	Surface Mounted Device
TTF	Time To Failure
VSWR	Voltage Standing-Wave Ratio

11. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLF6G15L-500H_6G15LS-500H v.2	20110916	Product data sheet	-	BLF6G15L-500H_6G15LS-500H v.1
Modifications:		<ul style="list-style-type: none"> The status of this data sheet has been changed to Product data sheet 		
BLF6G15L-500H_6G15LS-500H v.1	20110511	Objective data sheet	-	-

12. Legal information

12.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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14. Contents

1	Product profile	1
1.1	General description	1
1.2	Features and benefits	1
1.3	Applications	1
2	Pinning information	2
3	Ordering information	2
4	Limiting values	2
5	Thermal characteristics	3
6	Characteristics	3
6.1	Ruggedness in class-AB operation	3
7	Application information	4
7.1	Impedance information	4
7.2	Graphs	4
7.2.1	2-Tone	4
7.2.2	DVB-T	5
7.2.3	Reliability	6
7.3	Test circuit	7
8	Package outline	8
9	Handling information	10
10	Abbreviations	10
11	Revision history	10
12	Legal information	11
12.1	Data sheet status	11
12.2	Definitions	11
12.3	Disclaimers	11
12.4	Licenses	12
12.5	Trademarks	12
13	Contact information	12
14	Contents	13

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